Solid State Devices, Inc. 14701 Firestone Blvd * La Mirada, Ca 90638	SPD6638, SPD6642, SPD6643 SERIES
Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com Designer's Data Sheet Part Number/Ordering Information <sup>1/</sup> SPD	300 mA 50 - 125 VOLTS 4.5 - 6.0 nsec Hyper Fast Recovery RECTIFIER
$ \begin{array}{c}                                     $	<ul> <li>FEATURES:</li> <li>Hyper Fast Reverse Recovery Time 4.5 - 6 ns Max</li> <li>Hermetically Sealed</li> <li>Planar Passivated Chip</li> <li>For High Efficiency Applications</li> <li>Available in Axial &amp; Subminiature Square Tab Versions</li> <li>TX, TXV, and S-Level Screening Available<sup>2/</sup></li> <li>Replacement for 1N6638, 1N6642, 1N6643</li> <li>Low Thermal Resistance</li> <li>Metallurgical Class 3 Bond</li> </ul>

MAXIMUM RATINGS <sup>3/</sup>				
RATING		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage DC Blocking Voltage	SPD6638 SPD6642 SPD6643	V <sub>RWM</sub> V <sub>R</sub>	125 75 50	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, Tc = 25°C)		lo	300	mAmps
Peak Surge Current (8.3 msec Pulse, Half Sine Wave Superimposed on Io, allow equilibrium between pulses, $T_c = 25^{\circ}C$ )	junction to reach	I <sub>FSM</sub>	2.5	Amps
Operating & Storage Temperature		T <sub>OP</sub> and T <sub>STG</sub>	-65 to +175	°C
Thermal Resistance SMS- Junc Axial- Junction t	tion to End Tab o Lead @ .375"	R₀ <sub>JE</sub> R₀ <sub>JL</sub>	65 220	°C/W

## NOTES:

1/ For Ordering Information, Price, and Availability- Contact Factory.

 $\underline{\textbf{2}}$  / Screening Based on MIL-PRF-19500. Screening Flows Available on Request.

 $\underline{3}\prime$  Unless Otherwise Specified, All Electrical Characteristics @25°C.

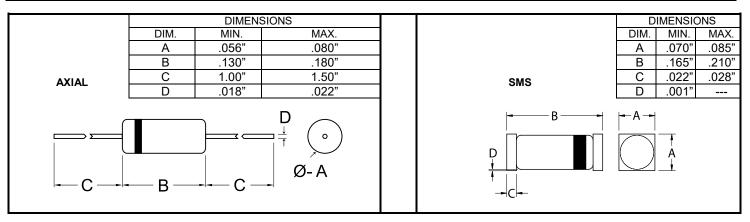




## SPD6638, SPD6642, SPD6643 **SERIES**

## ELECTRICAL CHARACTERISTICS 3/

CHARACTERISTICS		SYMBOL	VALUE	UNIT
Maximum Instantaneous Forward Voltage Drop (Pulsed, $T_A = 25^{\circ}C$ )	SPD6638 @ I⊧ = 10mA SPD6642 @ I⊧ = 10mA SPD6643 @ I⊧ = 10mA	V <sub>F1</sub>	0.8 0.8 1.0	Vdc
	SPD6638 @ I <sub>F</sub> = 200mA SPD6642 @ I <sub>F</sub> = 100mA SPD6643 @ I <sub>F</sub> = 100mA	V <sub>F2</sub>	1.1 1.2 1.2	Vdc
Maximum Instantaneous Forward Voltage Drop (Pulsed)	I <sub>F</sub> = 100mA, T <sub>A</sub> = -55°C	VF3	1.3	Vdc
Minimum Breakdown Voltage Ir = 100 μA	SPD6638 SPD6642 SPD6643	BvR	125 100 75	Vdc
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 25°C)	SPD6638 @ V <sub>R</sub> = 20V SPD6642 @ V <sub>R</sub> = 20V SPD6643 @ V <sub>R</sub> = 20V	I <sub>R1</sub>	35 25 50	nA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 25°C)	SPD6638 @ V <sub>R</sub> = 100V SPD6642 @ V <sub>R</sub> = 75V SPD6643 @ V <sub>R</sub> = 50V	I <sub>R2</sub>	500 500 500	nA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 150°C)	SPD6638 @ V <sub>R</sub> = 20V SPD6642 @ V <sub>R</sub> = 20V SPD6643 @ V <sub>R</sub> = 20V	I <sub>R3</sub>	50 50 75	μA
Maximum Reverse Leakage Current (300 μs Pulse Minimum , T <sub>A</sub> = 150°C)	SPD6638 @ V <sub>R</sub> = 100V SPD6642 @ V <sub>R</sub> = 75V SPD6643 @ V <sub>R</sub> = 50V	I <sub>R4</sub>	100 100 160	μA
Maximum Junction Capacitance ( $T_A = 25^{\circ}C$ , f = 1MHz) V <sub>R</sub> = 0V	SPD6638 SPD6642 SPD6643	CJ1	2.5 5.0 5.0	pf
Maximum Junction Capacitance ( $T_A = 25^{\circ}C$ , f = 1MHz) V <sub>R</sub> = 1.5V	SPD6638 SPD6642 SPD6643	C <sub>J2</sub>	2.0 2.8 2.8	pf
Maximum Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>RR</sub> = 1 mA)	SPD6638 SPD6642 SPD6643	trr	4.5 5.0 6.0	nsec



<b>NOTE:</b> All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RH0004F	DOC
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